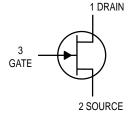
# **JFETs — General Purpose** N-Channel — Depletion



## 2N5457

\*Motorola Preferred Device



#### **MAXIMUM RATINGS**

| Rating  | Symbol           | Value       | Unit        |  |
|---|------------------|-------------|-------------|--|
| Drain-Source Voltage  | V <sub>DS</sub>  | 25          | Vdc         |  |
| Drain-Gate Voltage  | V <sub>DG</sub>  | 25          | Vdc         |  |
| Reverse Gate-Source Voltage   | V <sub>GSR</sub> | -25         | Vdc         |  |
| Gate Current  | IG               | 10          | mAdc        |  |
| Total Device Dissipation @ T <sub>A</sub> = 25°C<br>Derate above 25°C | PD               | 310<br>2.82 | mW<br>mW/°C |  |
| Junction Temperature Range  | TJ               | 125         | °C          |  |
| Storage Channel Temperature Range                                     | T <sub>stg</sub> | -65 to +150 | °C          |  |

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic  | Symbol                | Min         | Тур  | Max          | Unit  |
|---|-----------------------|-------------|------|--------------|-------|
| OFF CHARACTERISTICS   | •                     |             |      |              |       |
| Gate-Source Breakdown Voltage (I <sub>G</sub> = -10 μAdc, V <sub>DS</sub> = 0)  | V <sub>(BR)</sub> GSS | -25         | _    | _            | Vdc   |
| Gate Reverse Current $(V_{GS} = -15 \text{ Vdc}, V_{DS} = 0)$ $(V_{GS} = -15 \text{ Vdc}, V_{DS} = 0, T_A = 100^{\circ}\text{C})$ | lgss                  | _<br>_<br>_ | _    | -1.0<br>-200 | nAdc  |
| Gate-Source Cutoff Voltage<br>(V <sub>DS</sub> = 15 Vdc, I <sub>D</sub> = 10 nAdc)  | VGS(off)              | -0.5        | _    | -6.0         | Vdc   |
| Gate-Source Voltage<br>(V <sub>DS</sub> = 15 Vdc, I <sub>D</sub> = 100 μAdc)  | V <sub>GS</sub>       | _           | -2.5 | _            | Vdc   |
| ON CHARACTERISTICS  | •                     |             |      |              |       |
| Zero-Gate-Voltage Drain Current (1)<br>(V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0)  | IDSS                  | 1.0         | 3.0  | 5.0          | mAdc  |
| SMALL-SIGNAL CHARACTERISTICS  | •                     |             |      |              |       |
| Forward Transfer Admittance Common Source (1) (VDS = 15 Vdc, VGS = 0, f = 1.0 kHz)  | y <sub>fs</sub>       | 1000        | _    | 5000         | μmhos |
| Output Admittance Common Source (1)<br>(VDS = 15 Vdc, VGS = 0, f = 1.0 kHz)   | y <sub>os</sub>       | _           | 10   | 50           | μmhos |
| Input Capacitance<br>(V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)   | C <sub>iss</sub>      | _           | 4.5  | 7.0          | pF    |
| Reverse Transfer Capacitance<br>(V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)                                      | C <sub>rss</sub>      | _           | 1.5  | 3.0          | pF    |

<sup>1.</sup> Pulse Test; Pulse Width  $\leq$  630 ms, Duty Cycle  $\leq$  10%.

Preferred devices are Motorola recommended choices for future use and best overall value.



#### **TYPICAL CHARACTERISTICS**

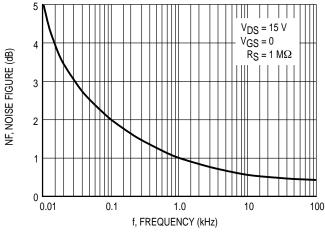


Figure 1. Noise Figure versus Frequency

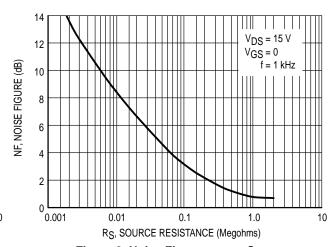


Figure 2. Noise Figure versus Source Resistance

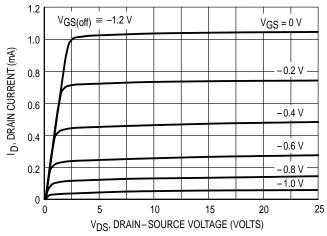


Figure 3. Typical Drain Characteristics

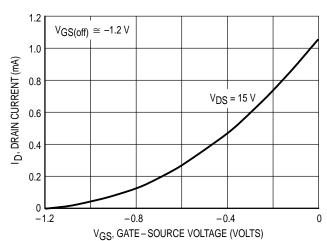


Figure 4. Common Source Transfer Characteristics

#### **TYPICAL CHARACTERISTICS**

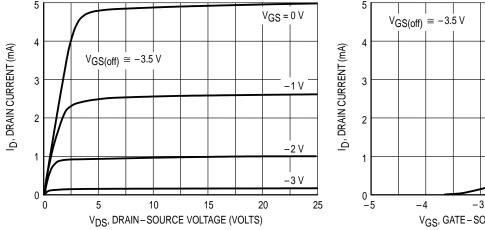


Figure 5. Typical Drain Characteristics

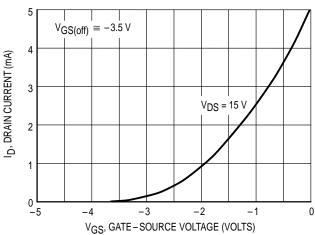
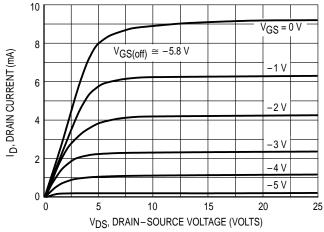


Figure 6. Common Source Transfer Characteristics



**Figure 7. Typical Drain Characteristics** 

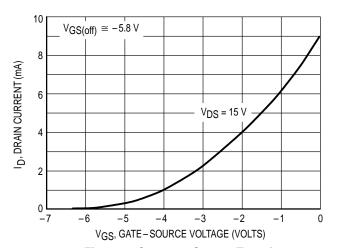
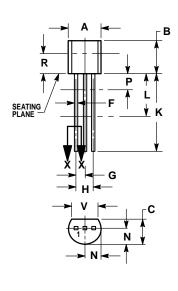


Figure 8. Common Source Transfer Characteristics

Note: Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%). Under dc conditions, self heating in higher IDSS units reduces IDSS.

#### PACKAGE DIMENSIONS



SECTION X-X

**CASE 029-04** (TO-226AA) **ISSUE AD** 

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
- CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L DIMENSION D AND J APPLY BETWEEN L AND K
  MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.175  | 0.205 | 4.45   | 5.20   |
| В   | 0.170  | 0.210 | 4.32   | 5.33   |
| C   | 0.125  | 0.165 | 3.18   | 4.19   |
| D   | 0.016  | 0.022 | 0.41   | 0.55   |
| F   | 0.016  | 0.019 | 0.41   | 0.48   |
| G   | 0.045  | 0.055 | 1.15   | 1.39   |
| Н   | 0.095  | 0.105 | 2.42   | 2.66   |
| J   | 0.015  | 0.020 | 0.39   | 0.50   |
| K   | 0.500  |       | 12.70  |        |
| L   | 0.250  |       | 6.35   |        |
| N   | 0.080  | 0.105 | 2.04   | 2.66   |
| Р   |        | 0.100 |        | 2.54   |
| R   | 0.115  |       | 2.93   |        |
| ٧   | 0.135  |       | 3.43   |        |

STYLE 5:

PIN 1. DRAIN

2. SOURCE

GATE

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